



## Reference Circuits

**Q1.** Figure 1 shows the low voltage band-gap reference circuit. W/L ratios of  $M_1$ ,  $M_2$  and  $M_3$  transistors are same, emitter area ratio between  $Q_1$  and  $Q_2$  is 1:8. Also, assume  $r_o = \infty$  and  $A = \infty$ . Ignore base current of BJT's.

- Derive the output voltage expression.
- According to expression in part (a), determine the ratios of  $R_3/R_1$  and  $R_2/R_1$  to provide 0.5V temperature independent output voltage. (Take  $V_{DD}=1$  V,  $V_{BE1}=0.7$  V,  $V_t=25$  mV and M factor is 23.5,  $M=(R_2/R_1)\ln(n)$ .)
- Explain intuitively (with hand calculation if possible) how the PTAT-reference circuit in the BGR can be stable. Consider two feedback loops formed by the op-amp given that one is positive feedback and the other negative. Is  $R_1$  critical in your argument?

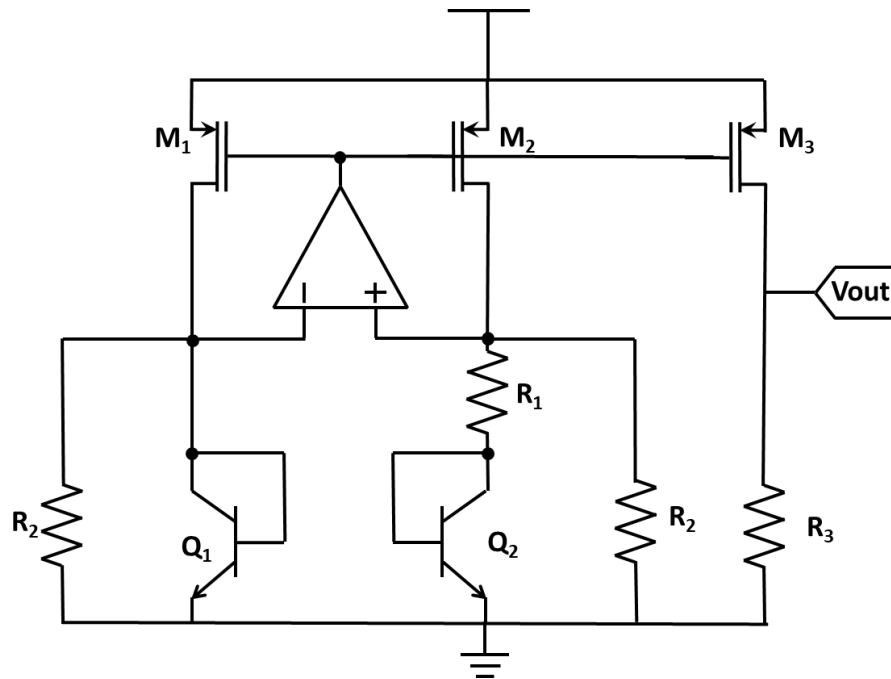
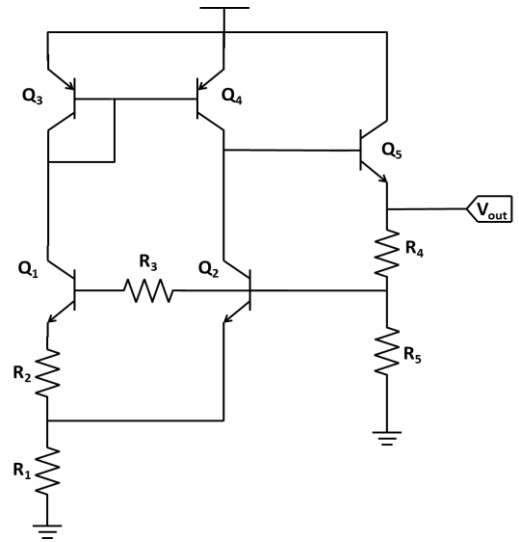


Figure 1. Low voltage band-gap reference circuit.

**Q2.** Figure 2 shows a band-gap reference circuit (BGR). Emitter area ratio between  $Q_1$  and  $Q_2$  is  $n:1$ . Answer the following questions.

- Ignore base currents of the of BJT`s and derive a closed-form expression for  $V_{out}$ . Find the ratio between  $R_1$  and  $R_2$  to get temperature independent BGR at 300K (Take  $dV_{BE}/dT = -1.5 \text{ mV/K}$  at 300K).
- Now, don't ignore base currents of  $Q_1$  and  $Q_2$  transistors and find expression for  $R_3$  resistor for eliminate the error due to base currents.



**Figure 2. Band-gap reference circuit**